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TCNQ Salts of Planar Metal Complex Cations: Novel Molecular Conductors and Semiconductors

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TCNQ SALTS OF PLANAR METAL COMPLEX CATIONS: NOVEL MOLECULAR CONDUCTORS AND SEMICONDUCTORS.

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Abstract The facile variation of positive charge of oxamide oxime metal complexes, caused by acid-base equilibrium, allows the growth of single crystals of their TCNQ salts. 1:1 salts consist of regular segregated stacks of the components, with metallic room temperature behaviour of the Ni compound, the Pt compound being a semiconductor. Room temperature conductivities are of the order of 10 Siemens per cm. A 2:3 Pt complex TCNQ salt contains segregated acceptor stacks with half a negative charge per molecule. These stacks run perpendicular to mixed stacks -D-D-A-D-D-A-, with integral charges on donors D and acceptors A.

INTRODUCTION

As a function of pH, the neutral bis(oxamide oximato) metal complexes of Ni(II), Pd(II), Pt(II), $[M(oaoH)_{2}]$, accept reversibly

one or two protons to yield monopositive or dipositive cations. From the ions $\left[\text{Ni}\left(\text{OaOH}_{2}\right)_{3}\right]^{2+}$ and $\left[\text{M}\left(\text{OaOH}_{2}\right)_{2}\right]^{2+}$, M=Pd, Pt, the salts $\left[\text{M}\left(\text{OaOH}\right)\left(\text{OaOH}_{2}\right)\right]^{\frac{1}{2}}$ TCNQ $^{-}$, M=Ni, Pd, Pt are obtained. During

crystal growth of the Pt compound, the 2:3 salts 2[Pt(oaoH) $(oaoH_2)$]⁺(TCNQ)₃²⁻ forms as a by-product.

STRUCTURES AND PROPERTIES

The three 1:1 salts with M=Ni, Pt, Pd are isomorphous. Crystals consist of segregated regular stacks of cations and anions (Figure 1). This structure is stabilized by H bridges between adjacent cations, and between cations and anions. The 2:3 salt exhibits the unusual feature of a $(TCNQ)^{-1/2}$ stack perpendicular to a -D-D-A-D-D-A- stack, with integral charges on donors and acceptors (Figure 2).

As expected for a single valent TCNQ salt, D.C. conductivity and thermopower of the 1:1 Pt salt indicate semiconducting behaviour, $\sigma RT \approx 5~\Omega^{-1} cm^{-1}$. Surprisingly, the Ni salt has a metallic regime at room temperature, $\sigma \approx 15~\Omega^{-1} cm^{-1}$. D.C. conductivity, thermopower, and EPR measurements (Figure 3) indicate a metal to semiconductor phase transition around 230K, but in the microwave conductivity the transition shows up around 170K (Figure 4).

CONCLUSIONS

The different behaviour of the Pt and Ni 1:1 salts hints at a mixed valence character of the latter one, caused by TCNQ^O doped into the TCNQ stack. The lack of negative charge may be compensated by proton vacancies in the metal complex stacks (raising the question of possible proton conductivity along these stacks). That TCNQ is partially oxidized to TCNQ during the crystal growth is evident by the formation of the 2:3 Pt salt. If the mixed valence character of the Ni salt can be confirmed, there is a chance to prepare solids with adjustable band filling without implying redox processes: The average charge per complex species may be controlled by the pH of the solution, and the TCNQ TCNQ ratio is easily varied by working with LiTCNQ/TCNQ mixtures.

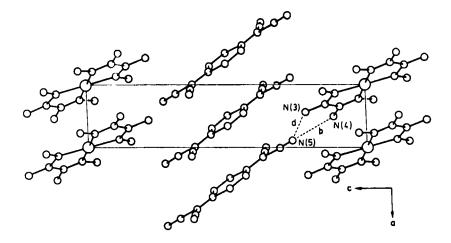


FIGURE 1 Structure of the 1:1 salts projected perpendicular to the stacks.

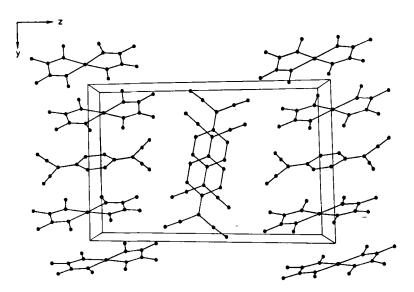


FIGURE 2 Structure of the 2:3 Pt salt projected along the TCNQ stack.

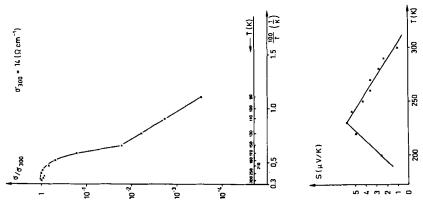
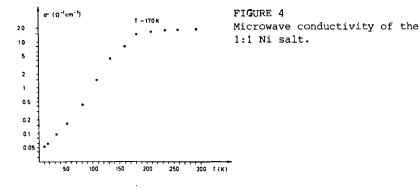


FIGURE 3 D.C. conductivity (left) and thermopower (right) of [Ni(oaoH)(oaoH₂)]TCNQ.



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